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**Electrical Characteristics**  $T_J = 25\text{ }^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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**Off Characteristics**

$BV_{DSS}$	Drain to Source Breakdown Voltage	$I_D = -250\text{ }\mu\text{A}$ , $V_{GS} = 0\text{ V}$	-20			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = -250\text{ }\mu\text{A}$ , referenced to $25\text{ }^\circ\text{C}$		-10		mV/ $^\circ\text{C}$
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = -16\text{ V}$ , $V_{GS} = 0\text{ V}$			-1	$\mu\text{A}$
$I_{GSS}$	Gate to Source Leakage Current	$V_{GS} = \pm 8\text{ V}$ , $V_{DS} = 0\text{ V}$			$\pm 10$	$\mu\text{A}$

**On Characteristics**

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = -250\text{ }\mu\text{A}$	-0.4	-0.5	-1.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = -250\text{ }\mu\text{A}$ , referenced to $25\text{ }^\circ\text{C}$		2.7		mV/ $^\circ\text{C}$
$r_{DS(on)}$	Static Drain to Source On Resistance	$V_{GS} = -4.5\text{ V}$ , $I_D = -2.0\text{ A}$		46	64	m $\Omega$
		$V_{GS} = -2.5\text{ V}$ , $I_D = -2.0\text{ A}$		53	71	
		$V_{GS} = -1.8\text{ V}$ , $I_D = -1.0\text{ A}$		59	79	
		$V_{GS} = -1.5\text{ V}$ , $I_D = -1.0\text{ A}$		68	95	
		$V_{GS} = -4.5\text{ V}$ , $I_D = -2.0\text{ A}$ , $T_J = 125\text{ }^\circ\text{C}$		54	84	
$g_{FS}$	Forward Transconductance	$V_{DD} = -5\text{ V}$ , $I_D = -3.8\text{ A}$		21		S

**Dynamic Characteristics**

$C_{iss}$	Input Capacitance	$V_{DS} = -10\text{ V}$ , $V_{GS} = 0\text{ V}$ , $f = 1\text{ MHz}$		1180	1570	pF
$C_{oss}$	Output Capacitance			190	255	pF
$C_{rss}$	Reverse Transfer Capacitance			160	225	pF

**Switching Characteristics**

$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = -10\text{ V}$ , $I_D = -3.8\text{ A}$ , $V_{GS} = -4.5\text{ V}$ , $R_{GEN} = 6\text{ }\Omega$		5.8	12	ns
$t_r$	Rise Time			5.9	12	ns
$t_{d(off)}$	Turn-Off Delay Time			311	498	ns
$t_f$	Fall Time			280	448	ns
$Q_g$	Total Gate Charge		$V_{GS} = 0\text{ V to } -4.5\text{ V}$		18	25
$Q_{gs}$	Gate to Source Charge	$V_{DD} = -10\text{ V}$ , $I_D = -3.8\text{ A}$		1.5		nC
$Q_{gd}$	Gate to Drain "Miller" Charge			4.7		nC

**Drain-Source Diode Characteristics**

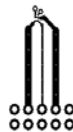
$V_{SD}$	Source to Drain Diode Forward Voltage	$V_{GS} = 0\text{ V}$ , $I_S = -1.1\text{ A}$ (Note 2)		-0.6	-1.2	V
$t_{rr}$	Reverse Recovery Time	$I_F = -3.8\text{ A}$ , $di/dt = 100\text{ A}/\mu\text{s}$		194	310	ns
$Q_{rr}$	Reverse Recovery Charge			344	550	nC

**Notes:**

1.  $R_{\theta JA}$  is determined with the device mounted on a  $1\text{ in}^2$  pad 2 oz copper pad on a  $1.5 \times 1.5\text{ in.}$  board of FR-4 material.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.



a.  $65\text{ }^\circ\text{C/W}$  when mounted on a  $1\text{ in}^2$  pad of 2 oz copper.

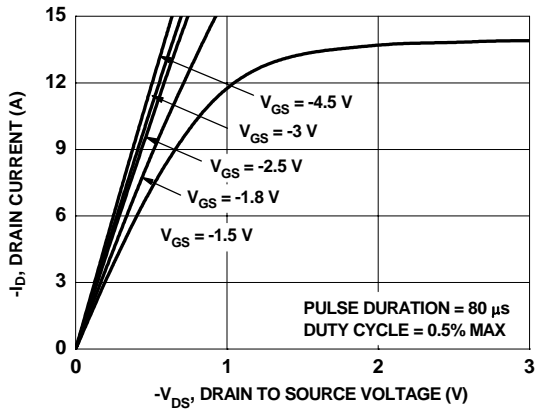


b.  $133\text{ }^\circ\text{C/W}$  when mounted on a minimum pad of 2 oz copper.

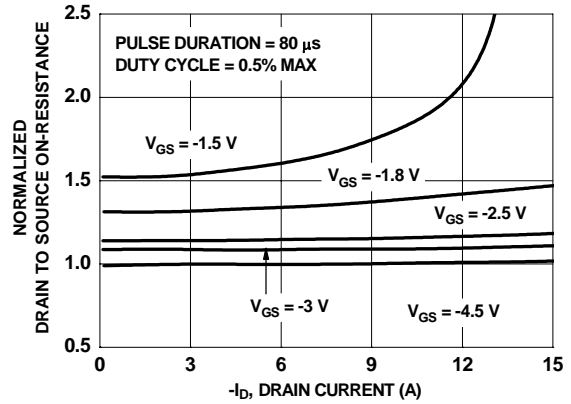
2. Pulse Test: Pulse Width <  $300\mu\text{s}$ , Duty cycle < 2.0%.

3. The diode connected between the gate and source serves only as protection ESD. No gate overvoltage rating is implied.

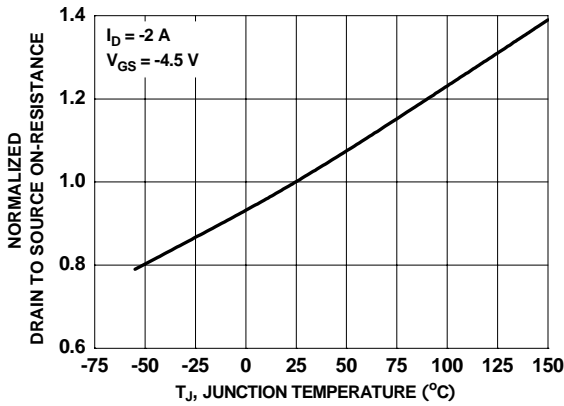
**Typical Characteristics**  $T_J = 25\text{ }^\circ\text{C}$  unless otherwise noted



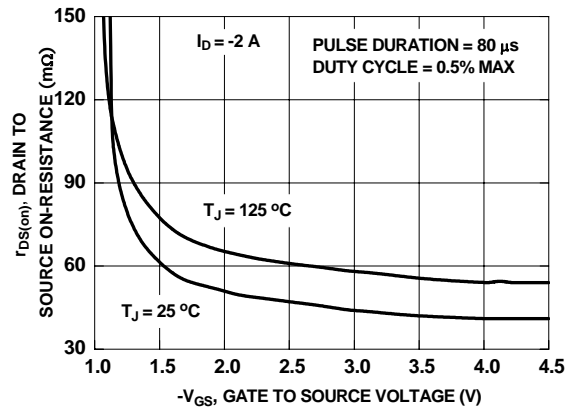
**Figure 1. On-Region Characteristics**



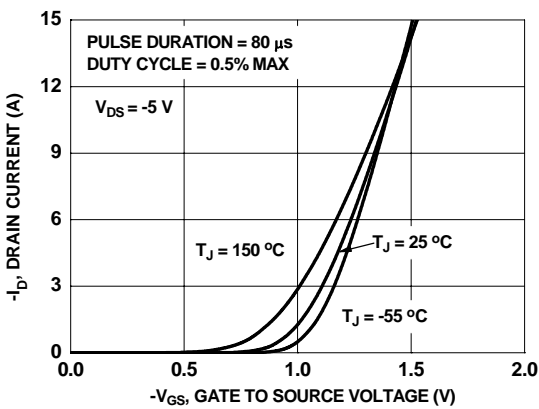
**Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage**



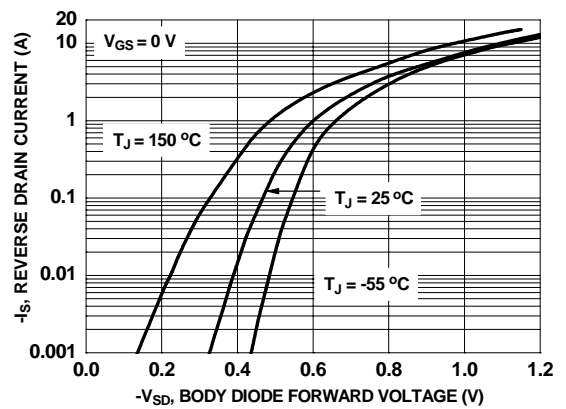
**Figure 3. Normalized On-Resistance vs Junction Temperature**



**Figure 4. On-Resistance vs Gate to Source Voltage**

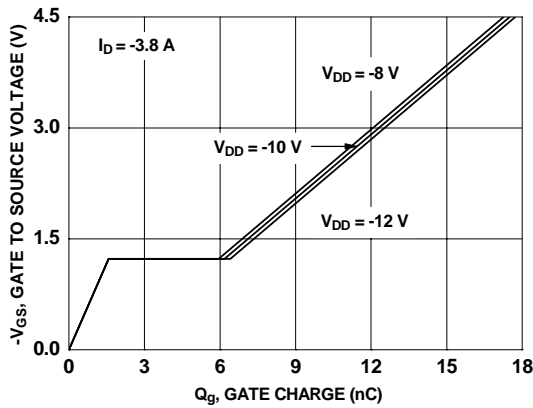


**Figure 5. Transfer Characteristics**

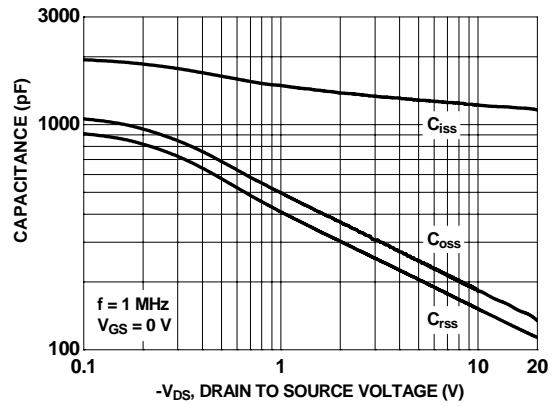


**Figure 6. Source to Drain Diode Forward Voltage vs Source Current**

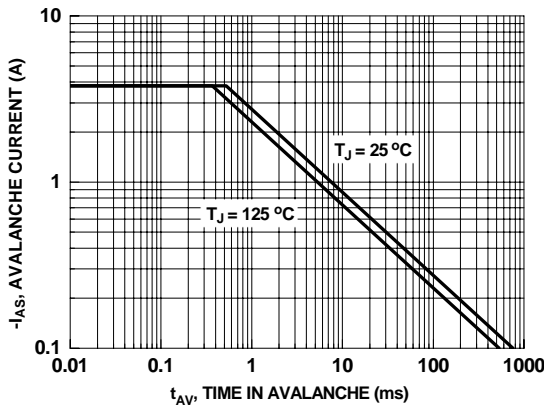
**Typical Characteristics**  $T_J = 25\text{ }^\circ\text{C}$  unless otherwise noted



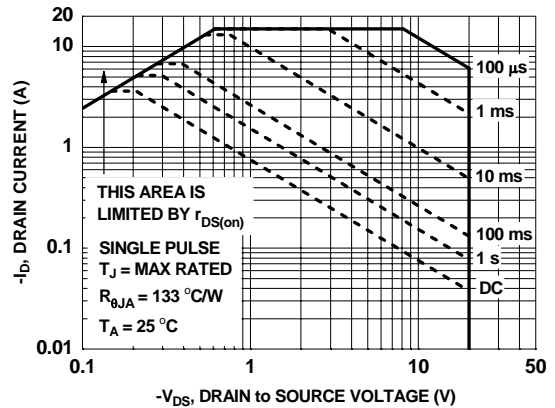
**Figure 7. Gate Charge Characteristics**



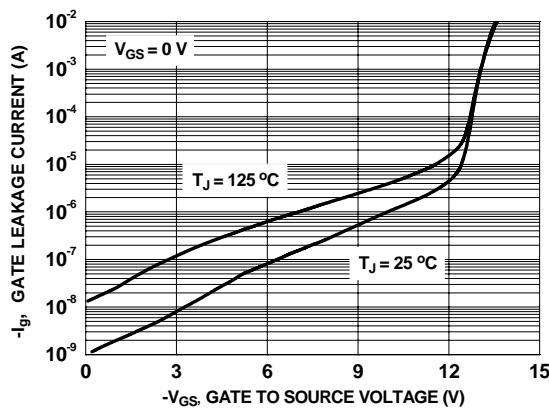
**Figure 8. Capacitance vs Drain to Source Voltage**



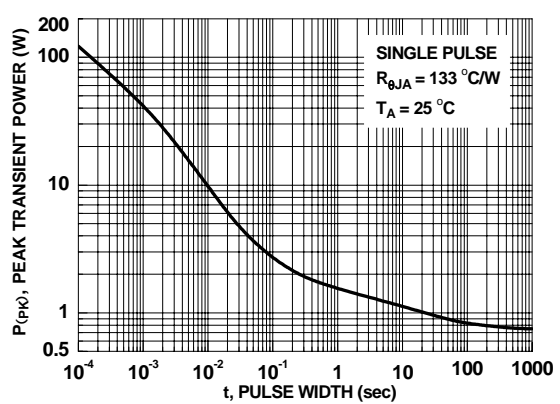
**Figure 9. Unclamped Inductive Switching Capability**



**Figure 10. Forward Bias Safe Operating Area**



**Figure 11. Gate Leakage Current vs Gate to Source Voltage**



**Figure 12. Single Pulse Maximum Power Dissipation**

**Typical Characteristics**  $T_J = 25\text{ }^\circ\text{C}$  unless otherwise noted

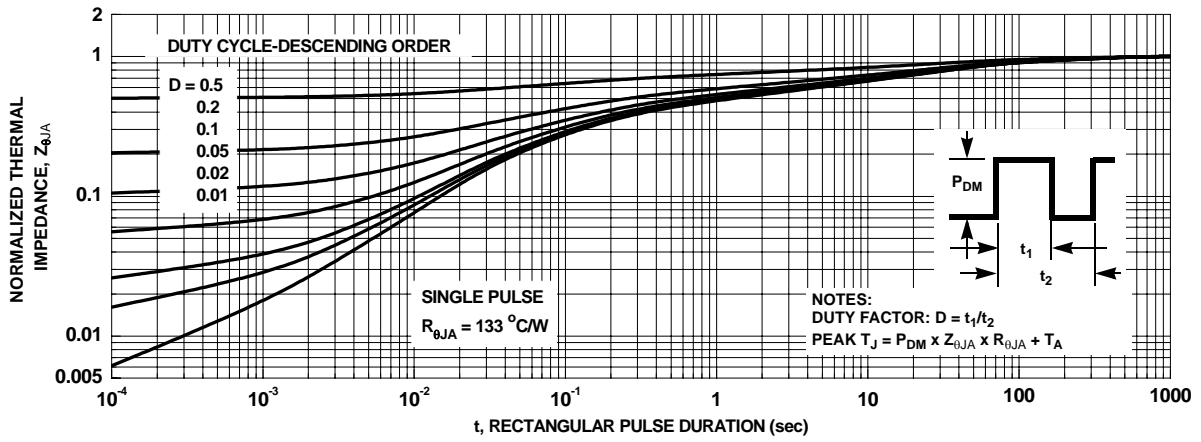
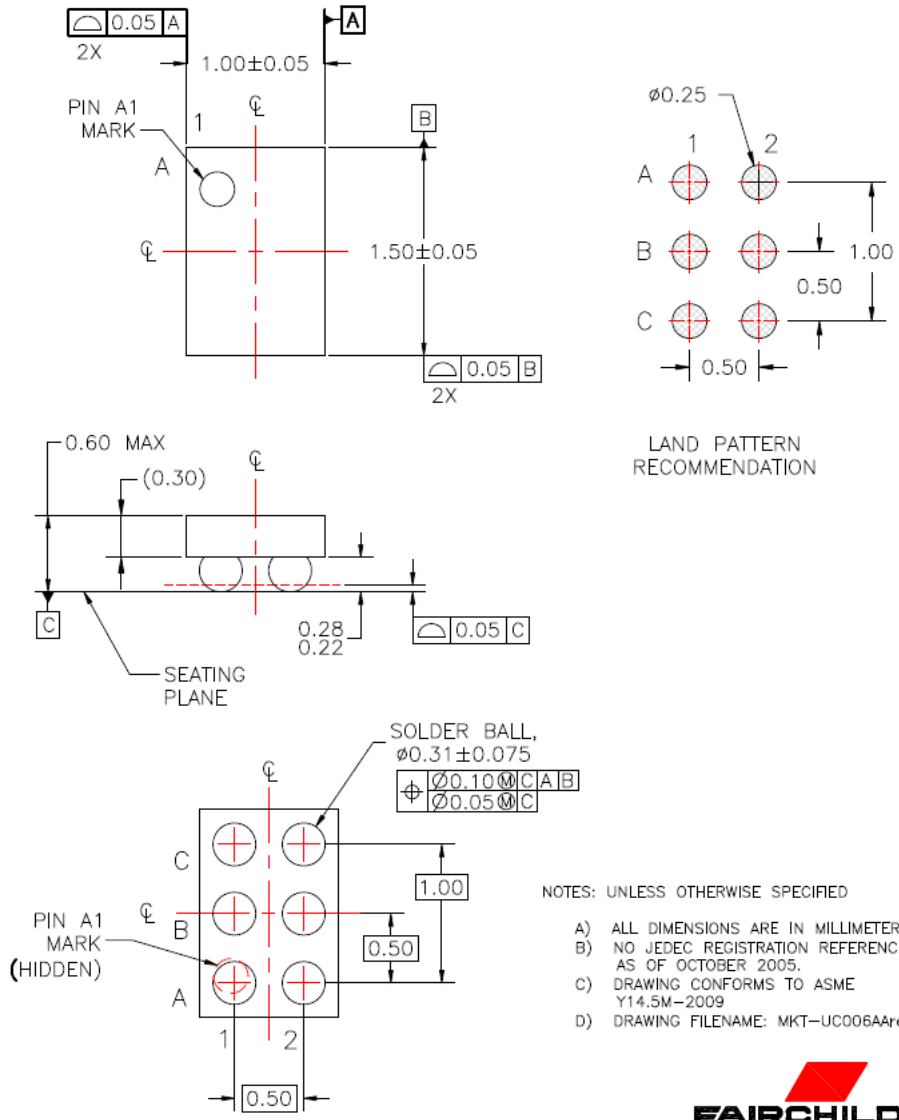


Figure 13. Transient Thermal Response Curve

### Dimensional Outline and Pad Layout



**Pin Definitions:**

Gate	Drain	Source
A1	C1, C2	A2, B1, B2






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